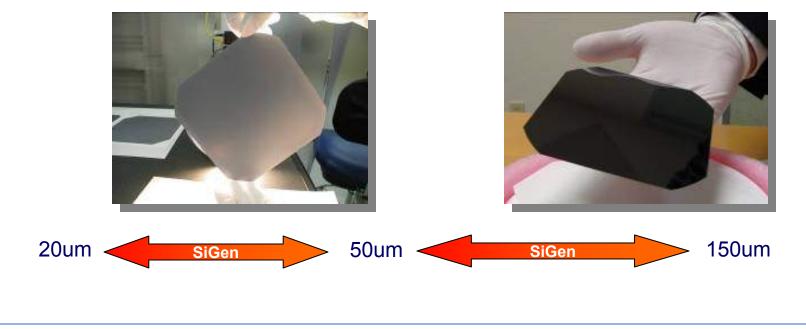
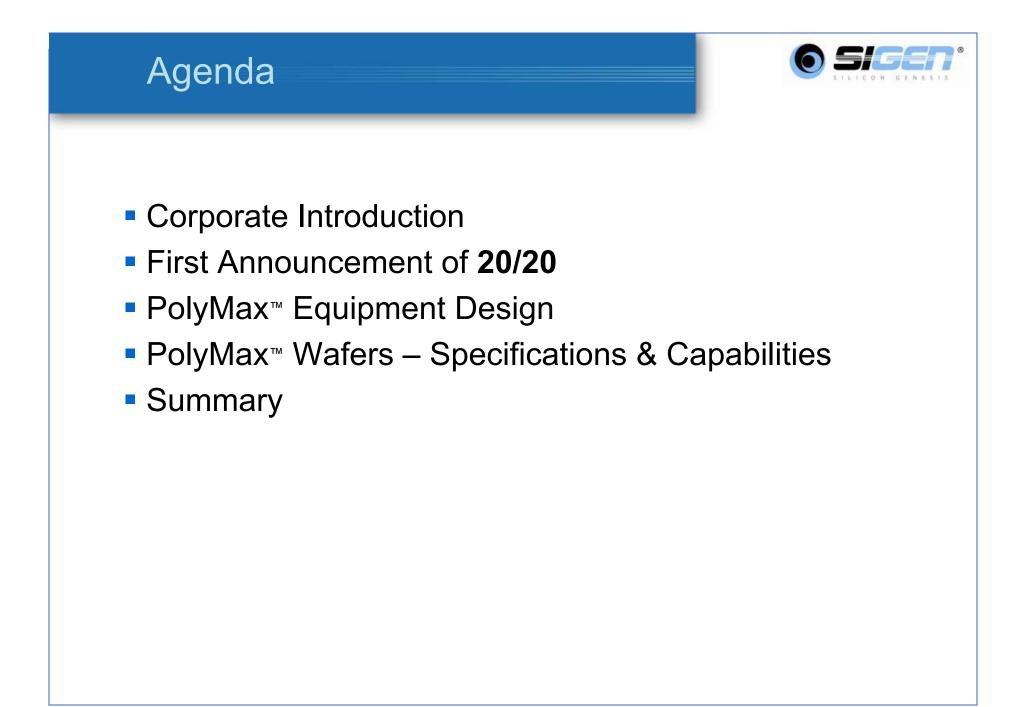




## Kerf-less wafer production

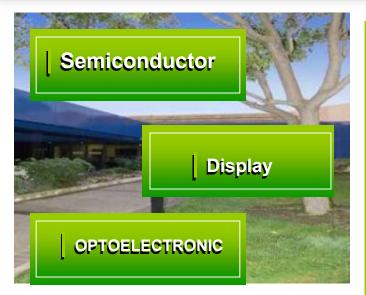
Francois Henley Silicon Genesis Corporation San Jose, California, USA





## **Company Overview**







- Founded in 1997
- Employees: 60 + external contract Eng/Mfg
- Headquartered in San Jose, California (Silicon Valley)
- Develops and licenses engineered substrate technology for semiconductor, optoelectronics and display markets
- Company's proprietary technologies
  - NanoCleave® (Layer-transfer)
  - NanoBond (Plasma-activated bonding)
  - NanoSmooth (Epi Smoothing/Epi Thickening)
- SiGen has extended its layer transfer expertise to the cleaving of mono-crystalline PV wafers for the solar industry
  - ■PolyMax<sup>™</sup>

### Solar Value Chain Needs CHANGE



- Renewable energy needs sustainable market
  Short-Mid Term
  - Lower cost and higher quality
  - Higher efficiency
  - Technology innovations



"Though the expected shake-out in the PV-industry, combined with the global recession, will result in the failure of many PV companies, those that **exhibit significant technological differentiation are likely to succeed**." – Greentechmedia – 12.17.08

•Longer-term  $\rightarrow$  Less dependency of government incentives

How to...

- 1. Differentiate wafer products?
- 2. Achieve "Best in Class" manufacturing margins?
- 3. Support wafer thickness roadmap?



### Learning Curve for Si Wafer PV



#### **Factors Driving Past Cost Reduction**

#### Upstream

- Poly silicon price:  $300/kg \rightarrow 100/kg$
- •Larger wafers:  $3^{"} \rightarrow 6^{"}$
- Thinner wafers: 350  $\mu m \rightarrow 225 \ \mu m$

#### Downstream

- Improved efficiency:  $10\% \rightarrow 16\%$
- •Volume manufacturing:  $1MW \rightarrow 100MW$
- Increased automation: none  $\rightarrow$  some
- Improved manufacturing processes

#### **Factors Driving Near Future Cost Reduction**

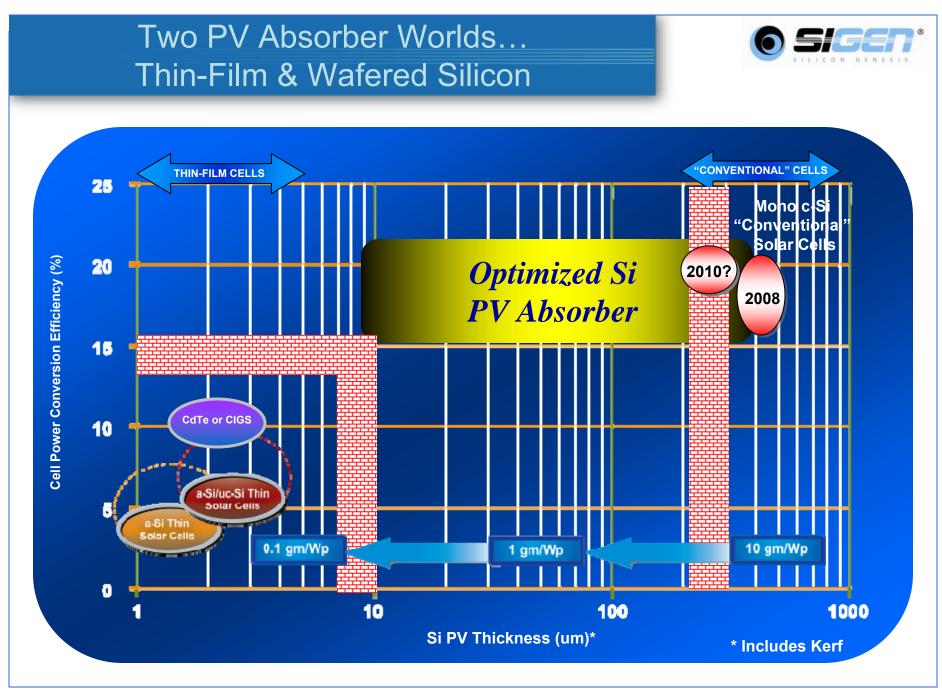
- Recovery of Poly supply
- Economies of Scale
- Even thinner wafers:  $\rightarrow$  150  $\mu$ m

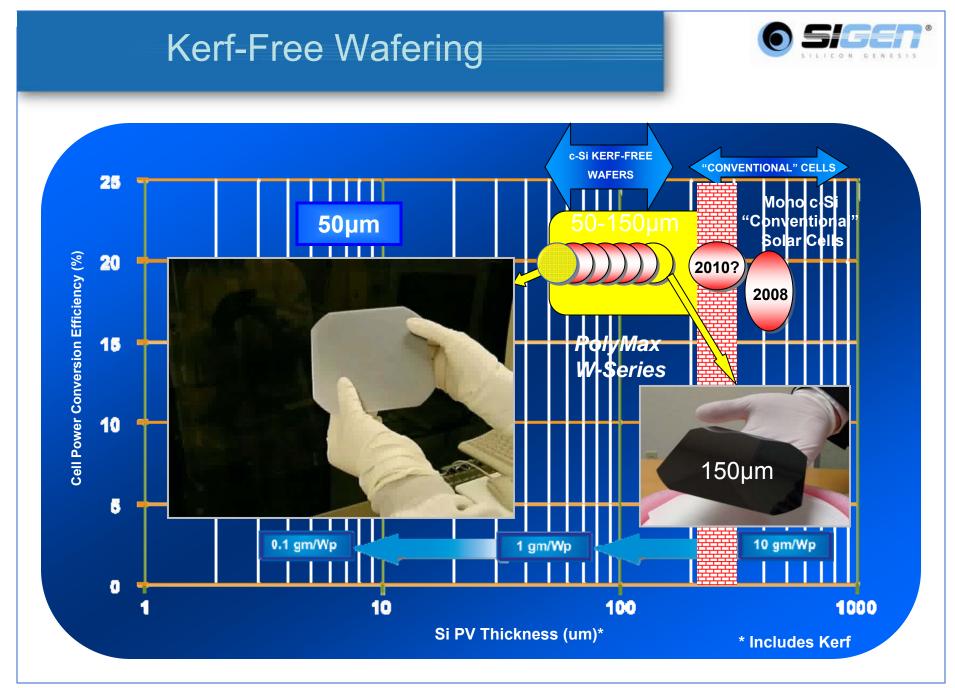
- Improved efficiency: 16%  $\rightarrow$  20%
- Volume manufacturing:  $\rightarrow$  1GW
- Advanced processing

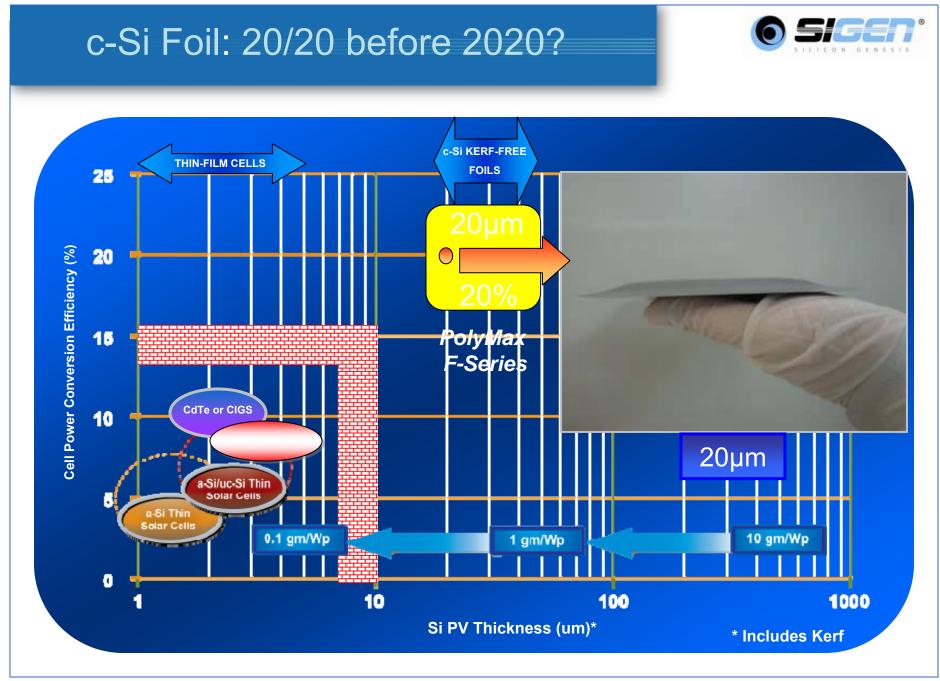
#### SiGen Cost Reduction Contributions – Long Run

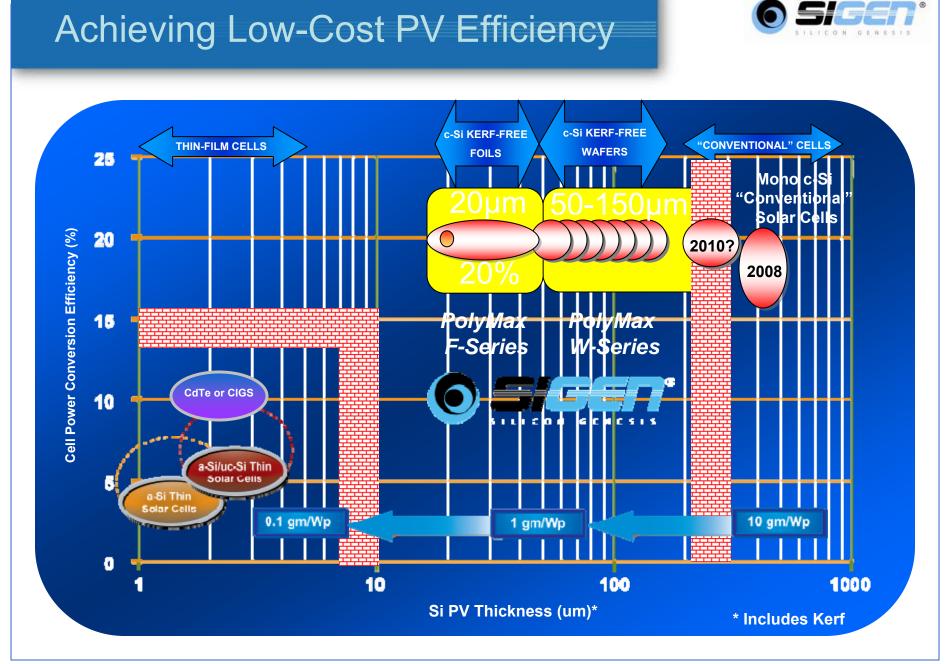
- Optimized use of Poly supply
- Even thinner wafers:  $100 \rightarrow 50 \ \mu m$

- Advanced processing
- Better yield for downstream







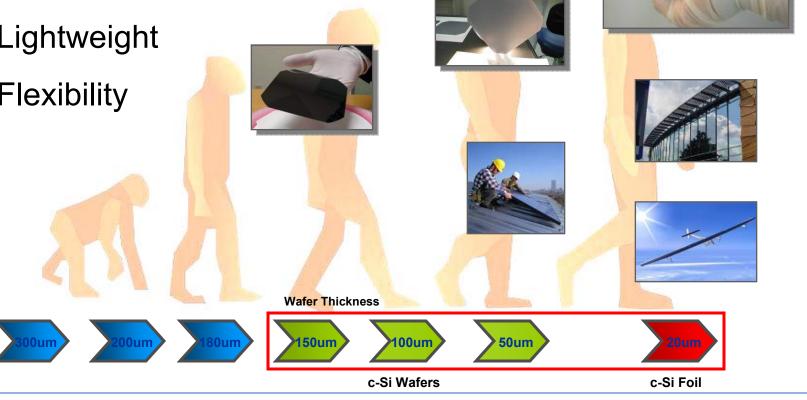


Future opportunities for thinner wafers



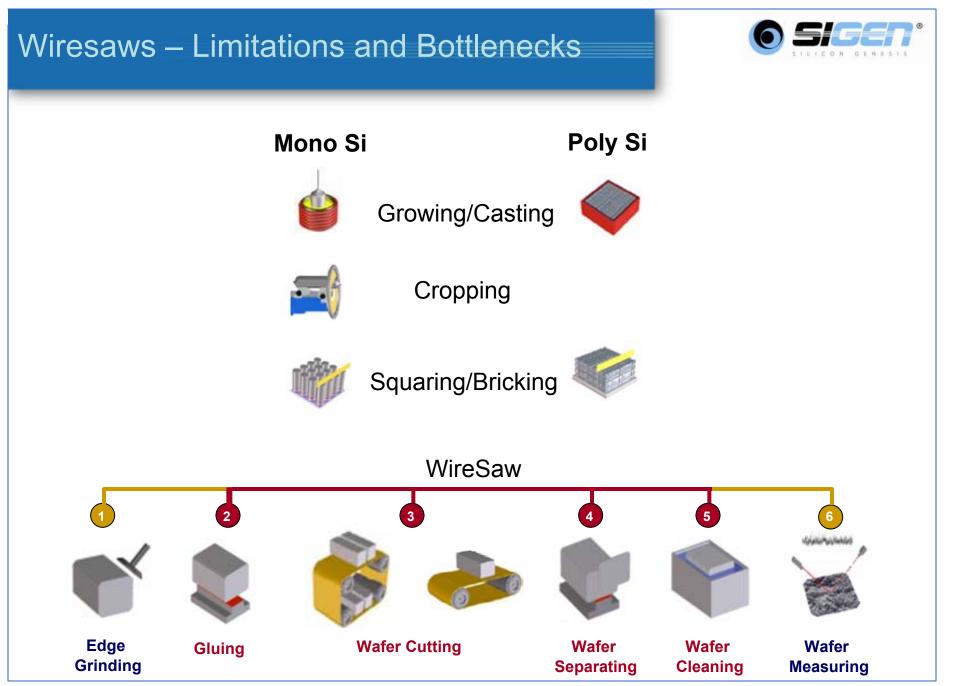
Thinner wafers opportunities

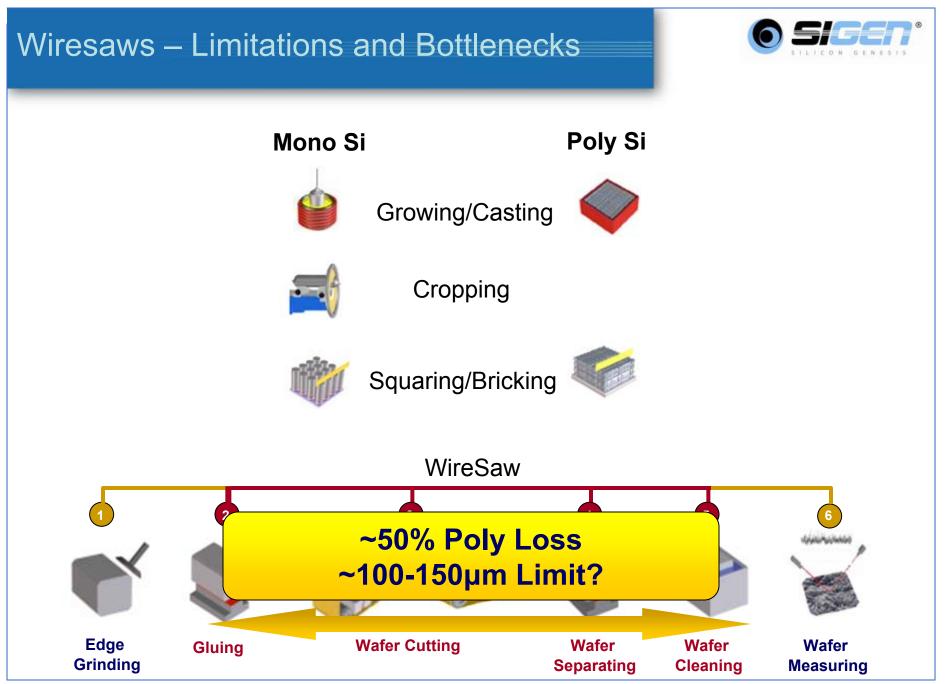
- Further cost reduction
- Enhanced rear illumination
- Lightweight
- Flexibility

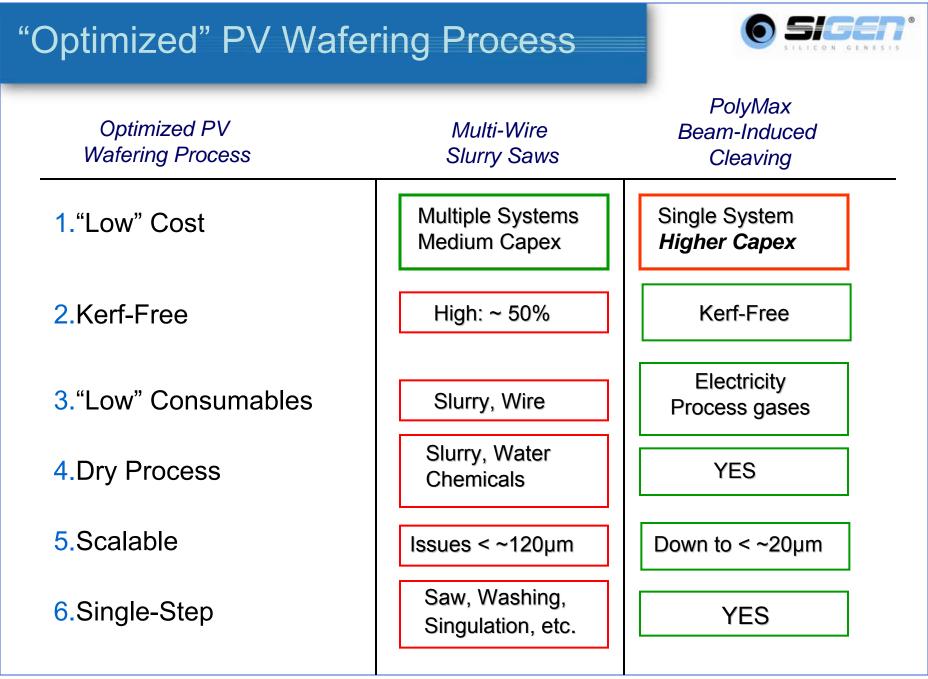


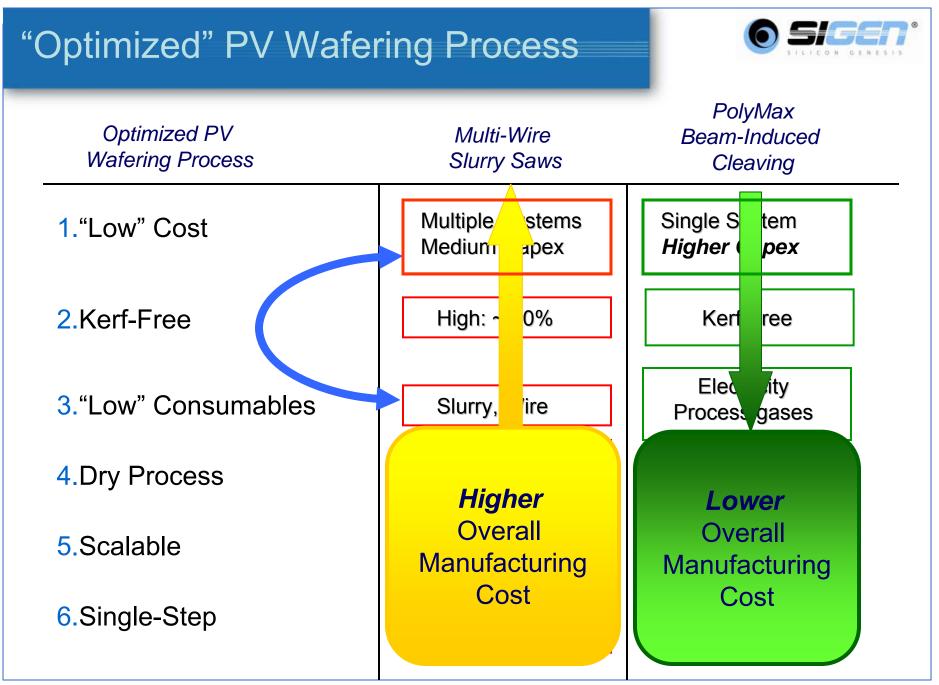
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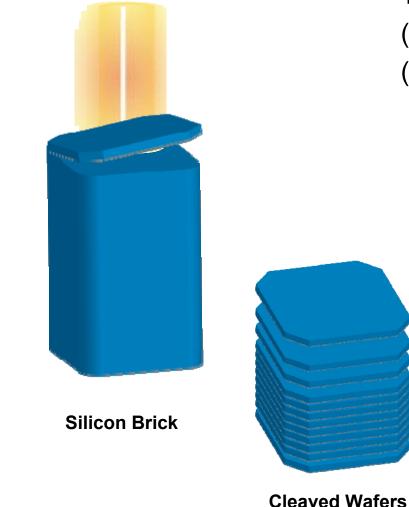




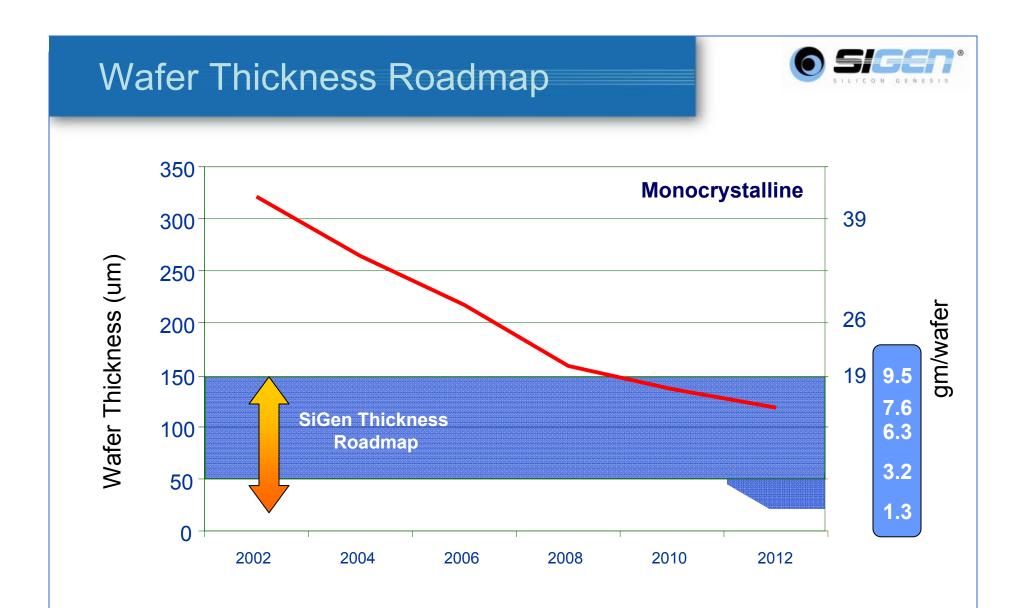


#### SiGen PolyMax Process



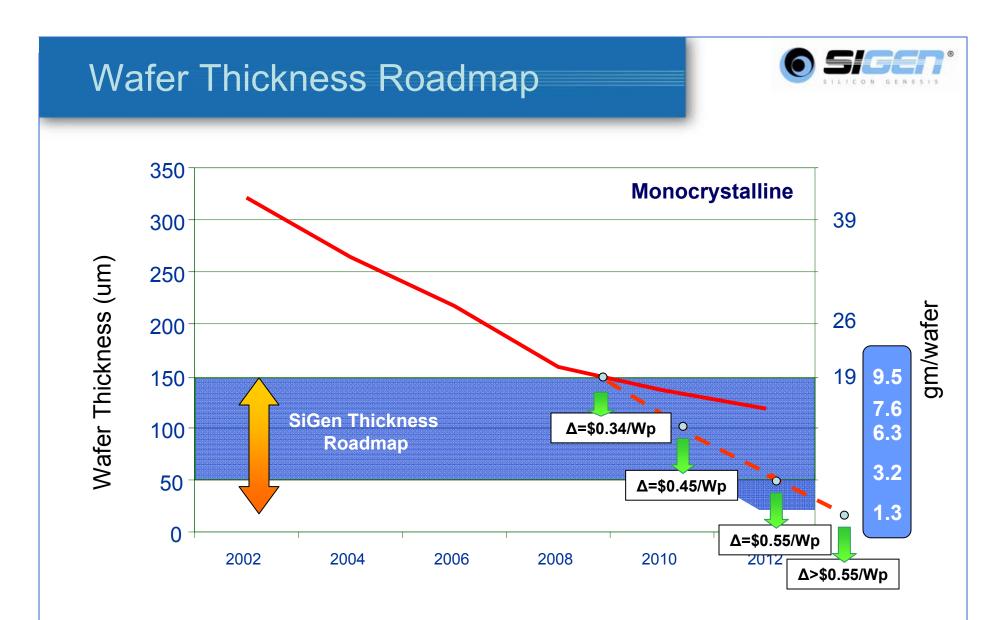


- Two Step Process
  - (1) Implant
  - (2) Cleave
    - What kerf less represents
      - Eliminates Consumables and Waste
        - SiC, Slurry, Wire
      - Eliminates Other Systems
        - Gluing
        - Singulation
        - Cleaning
      - Reduces Upstream CapEx
        - Less poly feedstock
        - Less CZ pullers
      - Develops thin wafer market
        - Removes the sub-150µm wafer barrier
        - New applications (i.e. BIPV)

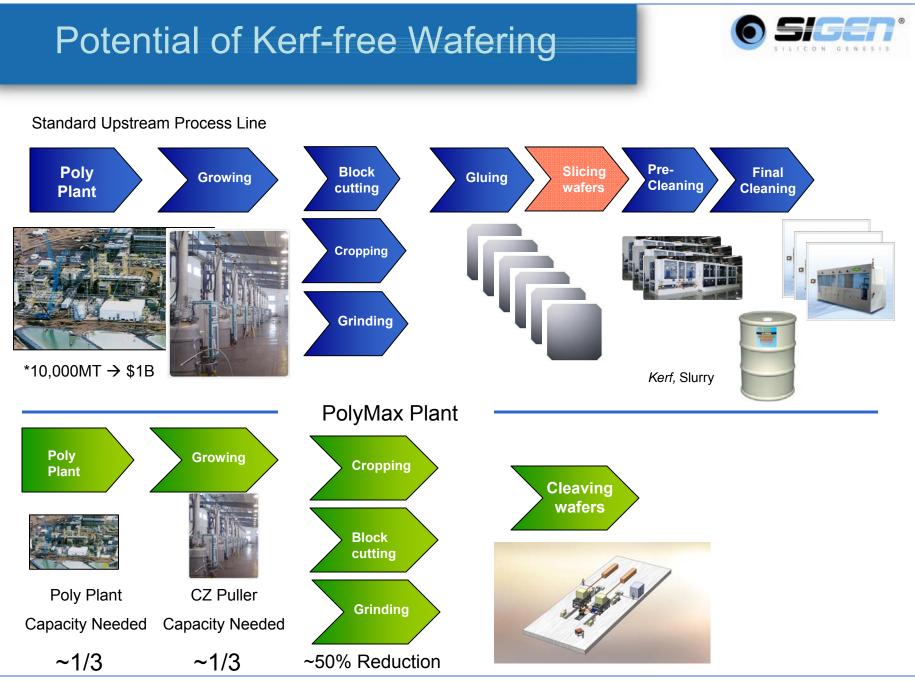


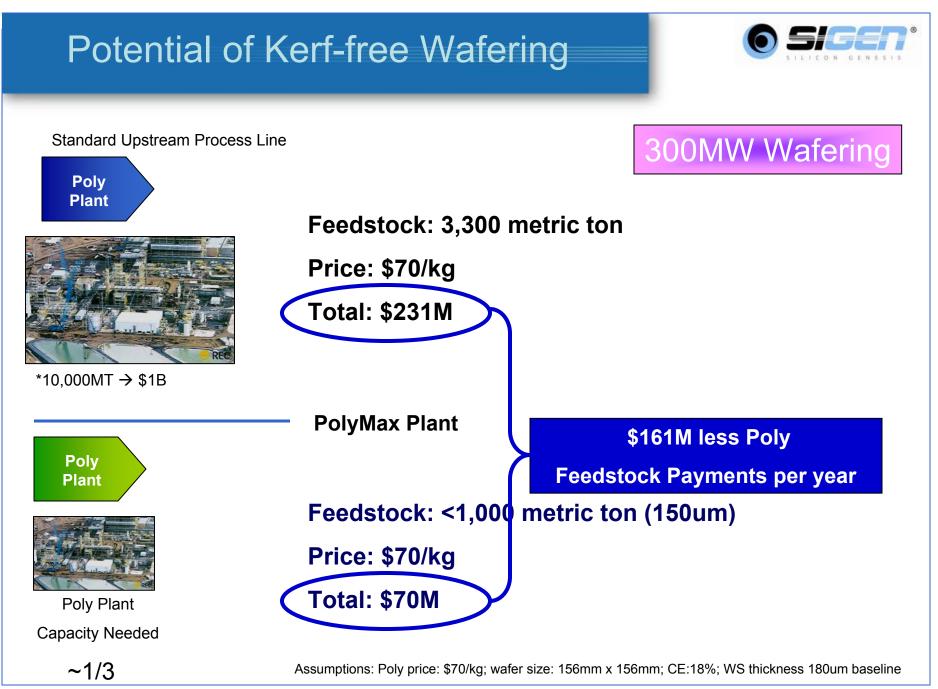
PolyMax will cover the wafer thickness roadmap with reduced gm/wafer and \$/Wp

Assumptions: Poly price: \$100/kg; wafer size: 156mm x 156mm; CE:16%; WS thickness 150um baseline



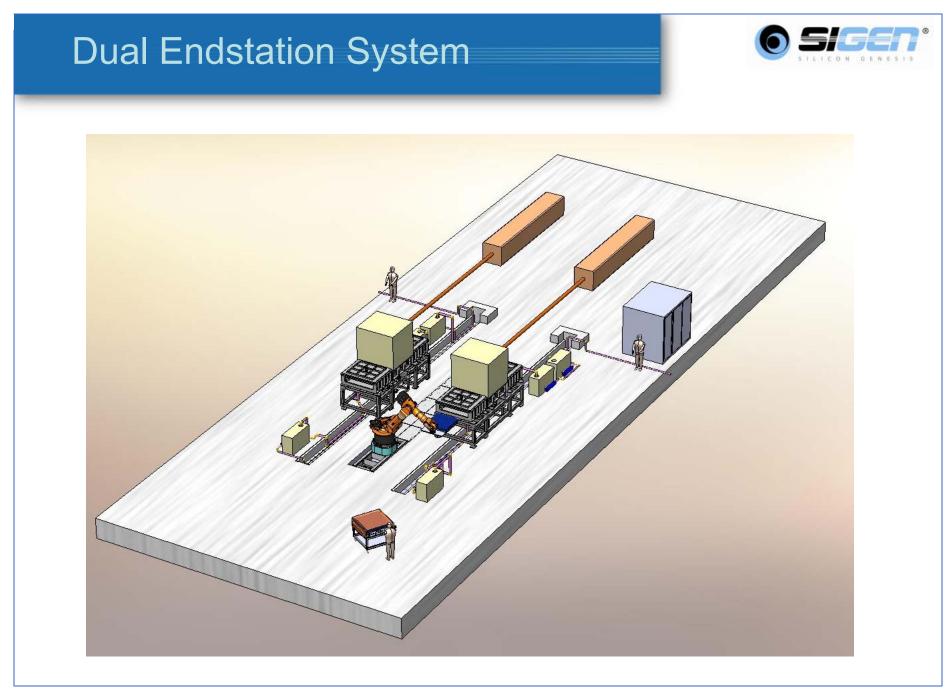
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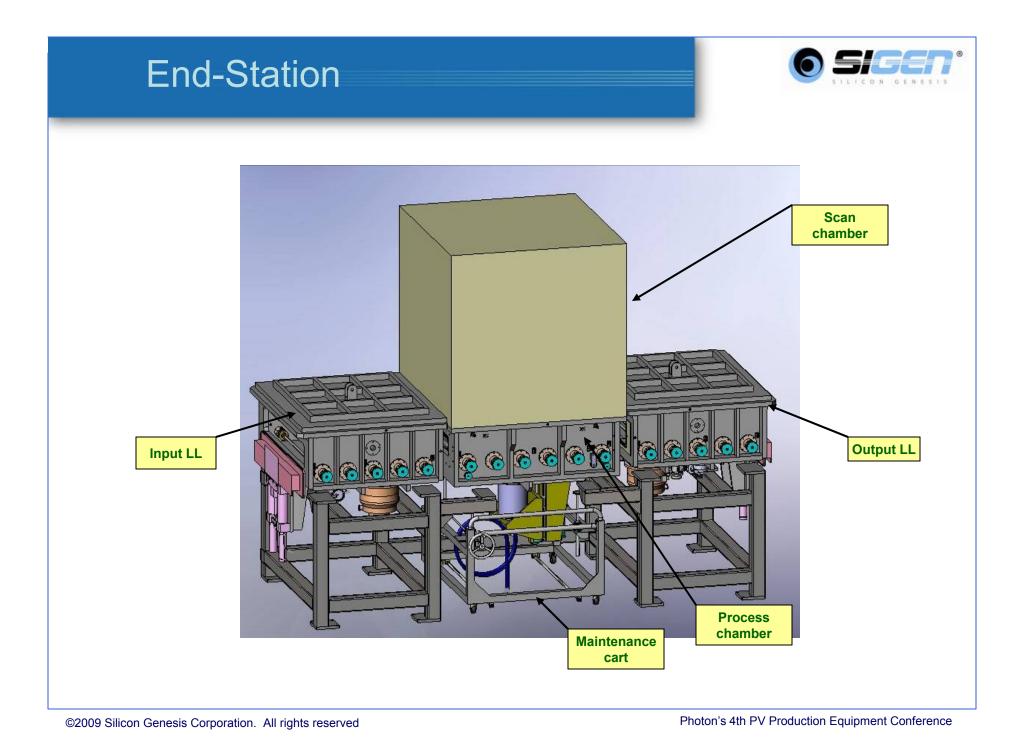






## PolyMax™ System Design

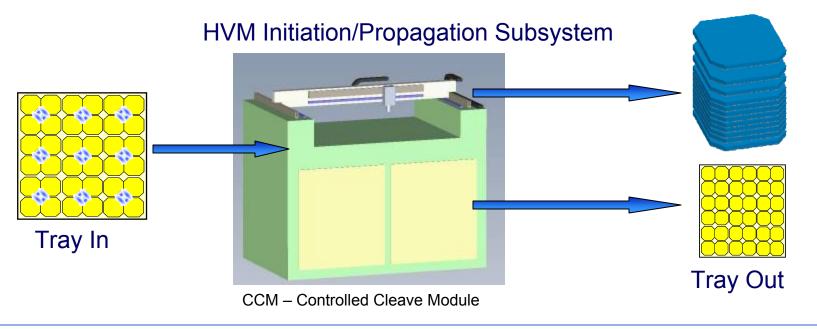




#### **HVM CCM Specifications**



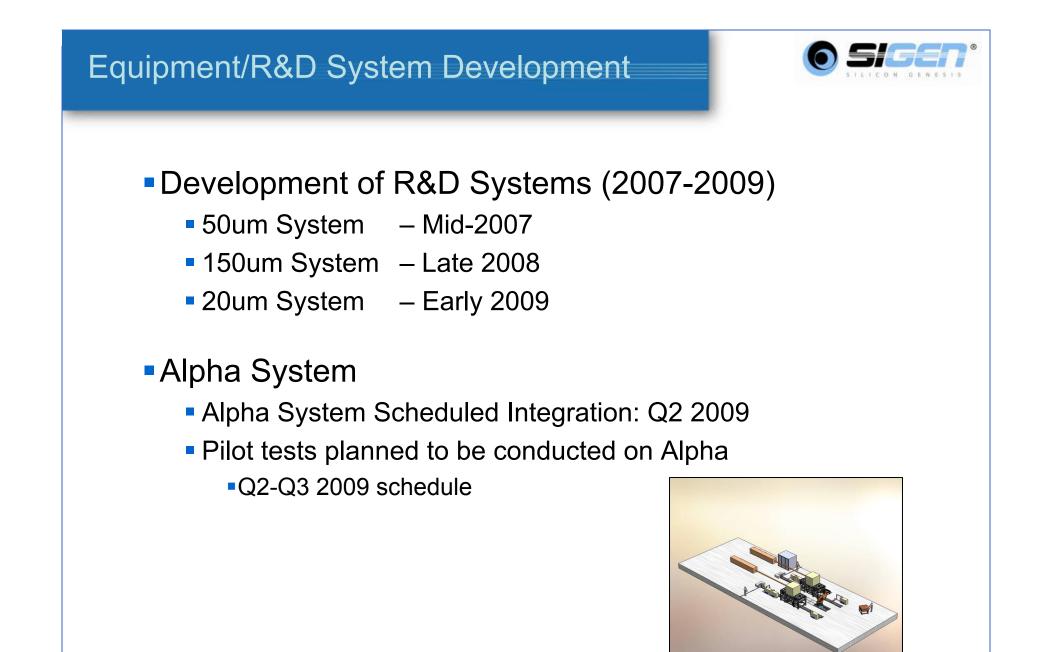
- The configuration consists of the following elements:
  - Propagation is caused by beam-induced cleaving
- Expected Propagation Process Time < 10 seconds per wafer</p>
- No tile handling/tray disassembly
- Cleaved film pick up is from top



**Cleaved Films** 

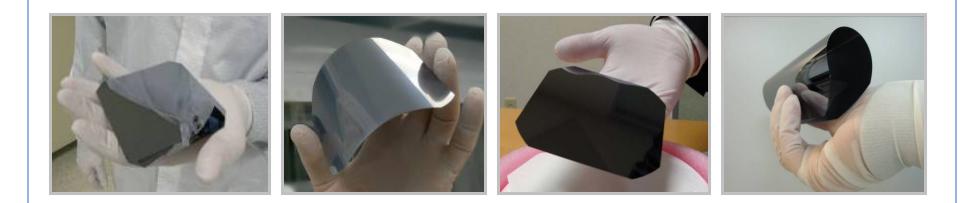


## PolyMax™ Development Status





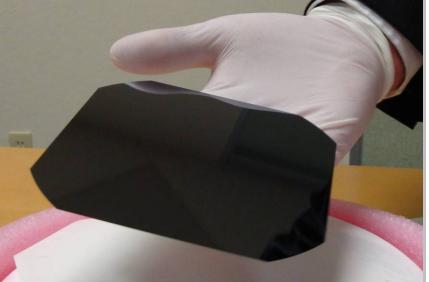
## PolyMax™ Wafers



### 150um Kerf-free Example



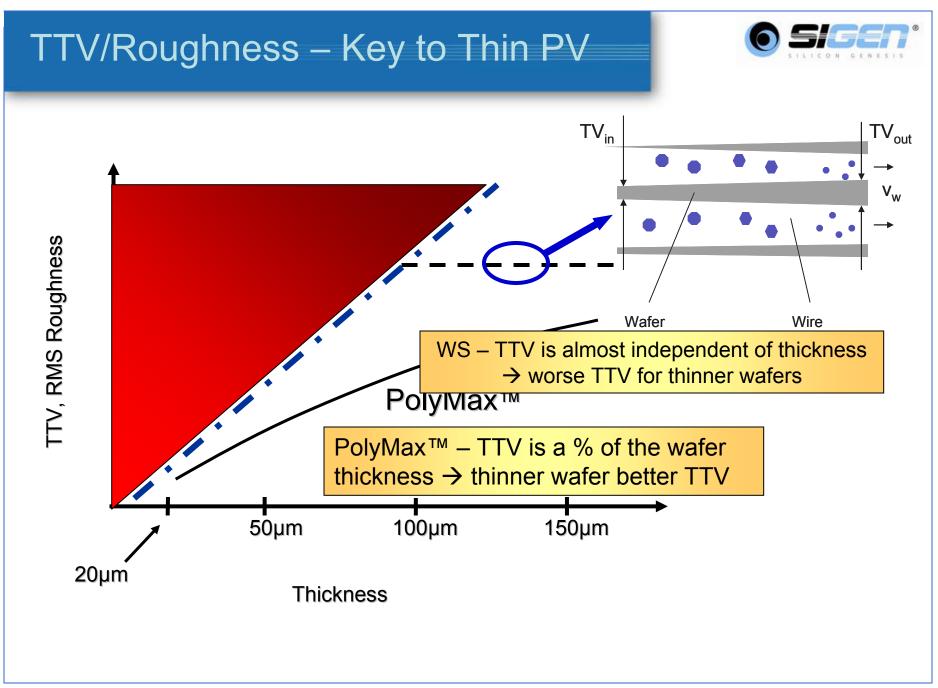


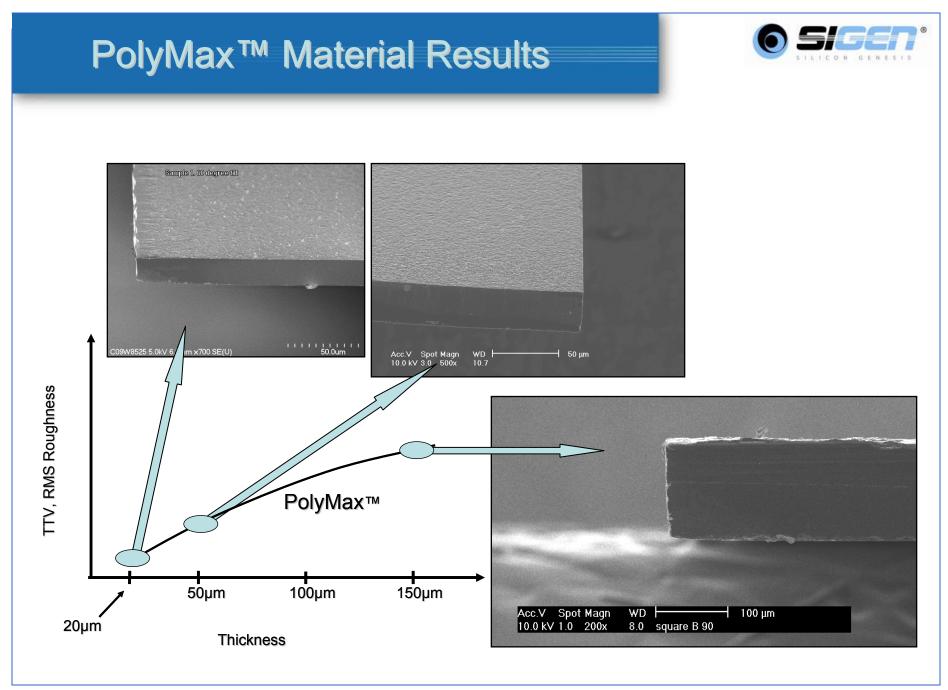


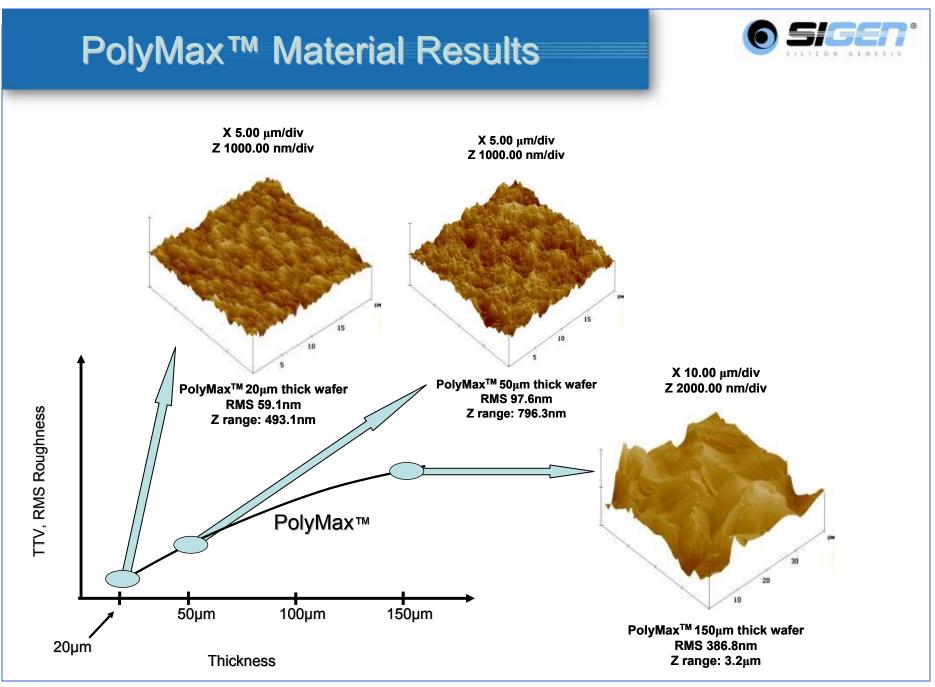
## Cleave Example – 150um Brick

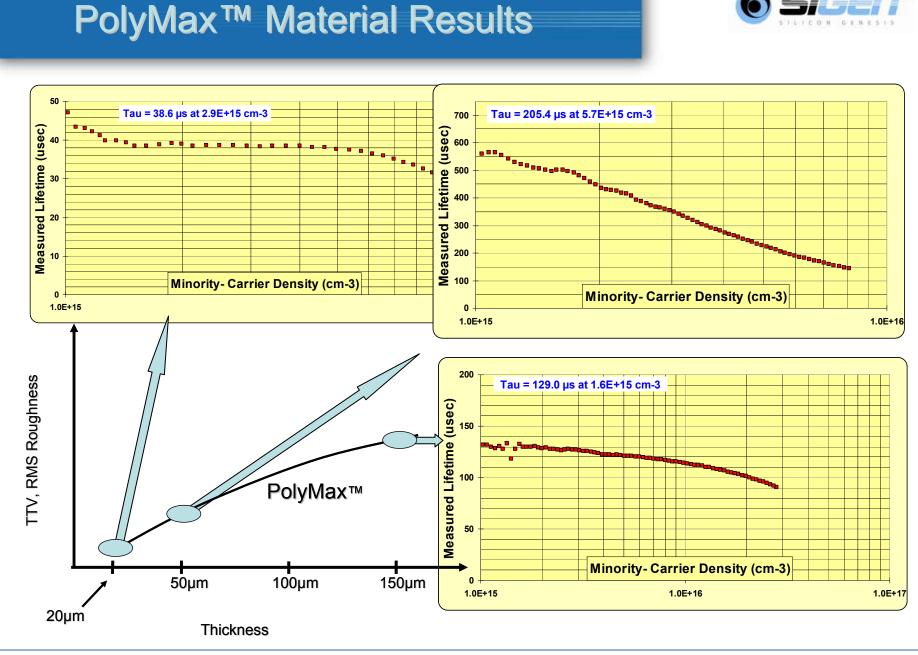












### Ex: 150um Wafer Specifications



- Lifetime
- BOW
- Resistivity
- Oxygen Conc.
- Carbon Conc.
- Dimension
- Thickness
- TTV
- Mechanical Strength
- Crystal Orientation

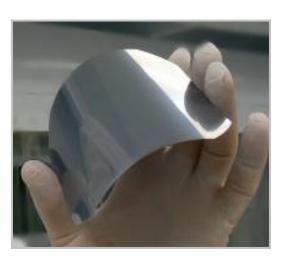
- >50µsec
- <35µm
- ~1-10  $\Omega$ -cm (defined by ingot)
- < ~1x10<sup>18</sup> cm<sup>-3</sup> (defined by ingot)
- < ~5x10<sup>16</sup> cm<sup>-3</sup> (defined by ingot)
- 125mm x 125mm & 156mm x 156mm
- 150µm +/- 5µm (as-cleaved)
- < ~ 10µm
- Higher than wiresaw
- (111)

### **Conclusions - Equipment**



Kerf-less wafering equipment is real and practical

- High-Volume manufacturing equipment on target for 2009
- Direct Film Transfer is the enabling technology
  - Implant technology applied to low-cost production
  - Cleave technology for high productivity
  - Maintaining high material quality





Photon's 4th PV Production Equipment Conference

### **Conclusions – PV Industry**



- Kerf-free benefits are numerous for the PV Industry
  - 1. Lower overall cost through entire PV value chain
    - Poly feedstock savings
    - Upstream equipment savings (CZ pullers, cropping, etc.)
    - Lower Opex costs
    - Thinner & higher strength form factors
  - 2. Green footprint & waste reduction
    - Free of wire and slurry consumables
    - Smaller energy footprint
    - Free of recovery/waste treatment infractructure
  - 3. New Applications
    - Effective across residential to commercial to utility
    - Enables high-efficiency BIPV
    - Flexible high-efficiency PV



# Thank you!

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